

Temperature and chemical potential dependence of the parity anomaly in quantum anomalous Hall insulators

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The low-energy physics of two-dimensional quantum anomalous Hall insulators like (Hg,Mn)Te quantum wells or magnetically doped (Bi,Sb)Te thin films can be effectively described by two Chern insulators, including a Dirac as well as a momentum-dependent mass term. Each of those Chern insulators is directly related to the parity anomaly of planar quantum electrodynamics. In this work, we analyze the finite-temperature Hall conductivity of a single Chern insulator in $2 + 1$ space-time dimensions under the influence of a chemical potential and an out-of-plane magnetic field. At zero magnetic field, this nondissipative transport coefficient originates from the parity anomaly of planar quantum electrodynamics. We show that the parity anomaly itself is not renormalized by finite-temperature effects. However, it induces two terms of different physical origin in the effective action of a Chern insulator, which is proportional to the Hall conductivity. The first term is temperature and chemical potential independent, and solely encodes the intrinsic topological response. The second term specifies the nontopological thermal response of conduction and valence band states. In particular, we show that the relativistic mass of a Chern insulator counteracts finite-temperature effects, whereas its nonrelativistic mass enhances these corrections. Moreover, we extend our analysis to finite magnetic fields and relate the thermal response of a Chern insulator therein to the spectral asymmetry, which is a measure of the parity anomaly in orbital fields.

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I. INTRODUCTION

Back in the 1980s, Haldane proposed the first solid-state model of a quantum anomalous Hall (QAH) insulator by adding a parity-breaking¹ Dirac mass term to an otherwise gapless graphene structure [1]. Such a system features a nonzero Hall conductivity even in the absence of Landau levels (LLs). From a high-energy perspective, this model is directly related to the parity anomaly of planar quantum electrodynamics, which implies that it is not possible to quantize a single Dirac fermion in a parity-symmetric manner with zero Hall conductivity [2,3]. Strictly speaking, the Haldane model contains two Dirac fermions as it is based on the hexagonal lattice structure of graphene. However, by fine tuning the Haldane mass, one of the Dirac fermion mass gaps can be closed, whereas the other one remains open. In this parameter limit, the band structure contains a single gapless Dirac fermion with a nonzero Hall conductivity. This implies that in the Haldane model one of the Dirac fermions alone is suitable to realize the parity anomaly in $2 + 1$ dimensions. Hitherto, it was not possible to experimentally set up the Haldane model

in a crystalline structure.² Instead, another type of QAH insulators was predicted in spin-polarized topological insulators (TIs) like (Hg,Mn)Te quantum wells [4,5] or magnetically doped (Bi,Sb)Te thin films [6,7]. Their low-energy physics is captured by the superposition of two Chern insulators [8]. Similar to the Haldane model, the gap of one of these Chern insulators can be closed by magnetic doping of the system, whereas at the same time the second Chern insulator remains gapped. In this fine-tuned limit, the gapless Chern insulator realizes the parity anomaly as its contribution to the Hall conductivity is in general nonzero. Hence, the analysis of single Chern insulators, which is the main purpose of this work, allows to study measurable consequences of the parity anomaly in a solid-state material. In contrast to the Dirac fermions in the Haldane model, each Chern insulator is characterized by two different parity-breaking mass terms: a conventional Dirac mass, as well as momentum-dependent Newtonian mass. As the Hall conductivity of a single Chern insulator is unaltered if one takes the parity-symmetric zero-mass limit, both the Dirac as well as the momentum-dependent mass term are directly related to the parity anomaly. It was recently shown that the momentum-dependent mass term acts similar to a Wilson fermion in a lattice regularization of a pure

¹Instead of a parity-even Dirac mass term, initially studied by Semenoff in Ref. [39].

²So far, this model has been only realized in optical lattices [40,41].

Dirac system [9]. As such, it ensures an integer instead of a half-quantized Hall conductivity associated to a pure Dirac fermion [10,11].

The parity anomaly is a zero magnetic field effect because an external magnetic field breaks the parity symmetry at the classical level. However, it can be shown that even in quantizing magnetic fields the signatures of the parity anomaly persist. They remain encoded in the spectral asymmetry [12]. Below a critical magnetic field, the parity anomaly effectively adds one LL to the entire Hall response of a Chern insulator. Above this field, the magnetic field closes the Dirac mass gap and the system exhibits a conventional QH response [13].

All these findings do not incorporate thermal effects. So far, finite-temperature signatures in parity anomaly driven systems are restricted to pure Dirac models. Calculating the quantum effective action of these systems induces a temperature-dependent and thus large gauge-noninvariant Chern-Simons term originating from the parity anomaly [14–19]. While it was shown that this noninvariance is absorbed by higher-order nonperturbative corrections to the effective action [20–27], this feature still gives rise to a fundamental question: Does the parity anomaly get renormalized by thermal effects? Answering this question is not only relevant for the QAH effect in the materials mentioned above. It is especially important in the case of interfaces between ferromagnetic insulators and three-dimensional topological insulators, where a proximity-induced interface magnetization has been experimentally observed at high temperatures [28,29]. In this case, the out-of-plane magnetization causes a gap opening in the interface Dirac spectrum, which induces a parity anomaly on the TI surface and a concomitant magnetoelectric torque in the Landau-Lifshitz equation [30–32]. A similar effect is expected to occur on the surface of the recently discovered antiferromagnetic TI MnBi₂Te₄ [33,34], where the gap in the surface Dirac spectrum is an intrinsic feature of the system.

By definition, the parity anomaly only implies the breakdown of parity symmetry at the quantum level. This dictates a certain form of the band structure, which is temperature independent.³ Hence, the parity anomaly cannot obtain any finite-temperature correction. In contrast, the prefactor of the anomaly-induced Chern-Simons term in the effective action corresponds to the finite-temperature Hall conductivity. We calculate this nondissipative transport coefficient for Chern insulators including both a Dirac as well as a momentum-dependent mass. We studied these systems in the absence and presence of a magnetic field, as well as with and without particle-hole symmetry. This leads to the following results: (i) The parity anomaly induces a topological part in the Hall conductivity which is temperature as well as chemical potential independent and described by the Chern number. (ii) The nonquantized finite-temperature and chemical potential corrections to the Hall conductivity also originate from the parity anomaly since they also depend on the band structure.

³Rigorously, this statement is only true for small temperatures. For very large temperatures the system can deform, which essentially changes the band structure. However, this scenario is beyond the scope of our analysis.

However, they do not depend on its topology, being rather related to the temperature-dependent filling of the valence and conduction bands. As expected, an increasing Dirac mass counteracts finite-temperature effects. On the other hand, we show that in the nontrivial phase an increasing Newtonian mass enhances the finite-temperature corrections. (iii) In finite magnetic fields, the thermal LL response renormalizes the parity anomalous part of the Hall conductivity. In the Dirac mass gap it adds to the otherwise quantized parity anomaly related contribution.

This work is structured as follows: In Sec. II, we discuss the relation of magnetically doped two-dimensional TIs to the parity anomaly and compare these systems to the Haldane model. In this context, we analyze the band structure of Chern insulators in the absence and presence of an out-of-plane magnetic field and with, as well as without, particle-hole symmetry. In Secs. III and IV, we analyze the parity-odd transport of a Chern insulator for a finite temperature and chemical potential, as well as for zero and finite magnetic fields, respectively. In Sec. V we summarize our results and give an outlook.

II. PARITY ANOMALY IN A QAH SYSTEM BEYOND THE HALDANE MODEL

In this work, we consider (2 + 1)-dimensional Chern insulators which are defined by two different mass terms: a momentum-independent Dirac mass m , as well as a momentum-dependent Newtonian mass term $B|\mathbf{k}|^2$. The Lagrangian of such an insulator is given by

$$\mathcal{L} = \bar{\psi}(A\gamma_\mu k^\mu - m + Bk_i k^i)\psi, \quad (1)$$

where ψ and $\bar{\psi} = \psi^\dagger \gamma_0$ are the two-component Dirac spinor and its adjoint $\gamma_\mu = (\sigma_3, i\sigma_2, i\sigma_1)$ are the (2 + 1)-dimensional Dirac matrices, and we consider the metric $g^{\mu\nu} = \text{diag}(+, -, -)$. Here and throughout the paper, greek indices run over the space-time coordinates $\{0, 1, 2\}$, while roman indices run over the spatial components $\{1, 2\}$ only. Moreover, the parameter A is proportional to the Fermi velocity and $\sigma_{1,2,3}$ define the Pauli matrices. In comparison to a pure Dirac Lagrangian, the additional Newtonian mass term in Eq. (1) breaks the Lorentz symmetry as it only involves spatial momenta. Let us close the discussion of Eq. (1) by noticing that a similar Lagrangian can also be used for the description of (2 + 1)-dimensional superfluid Fermi liquids, as it is for instance described in Ref. [35].

The first-quantized Hamiltonian associated to Eq. (1) can be derived by a Legendre transformation:

$$\mathcal{H} = A(k_1\sigma_1 - k_2\sigma_2) + (m - B\alpha)\sigma_3. \quad (2)$$

Here, we introduced the abbreviation $\alpha = k_1^2 + k_2^2$. Both of the mass terms in Eq. (2), m and $B\alpha$, break the parity symmetry of the Hamiltonian. In 2 + 1 dimensions, parity symmetry is defined as invariance of the theory under $\mathcal{P} : (x_0, x_1, x_2) \rightarrow (x_0, -x_1, x_2)$. Consequently, the Dirac as well as the Newtonian mass contribute to the integer Chern number⁴[10,11]

$$\mathcal{C}_{\text{CI}} = [\text{sgn}(m) + \text{sgn}(B)]/2. \quad (3)$$

⁴Adding higher-order momentum-dependent mass corrections to the Hamiltonian of a Chern insulator changes its Chern number.

Even in the parity-symmetric limit $m, B \rightarrow 0^\pm$, the two-dimensional Chern number C_{CI} does not vanish for $\text{sgn}(m/B) > 0$. This effect is known as the parity anomaly of Dirac-type systems in odd space-time dimensions. Initially, the parity anomaly has been predicted for a pure Dirac spectrum in Ref. [3]. Due to the absence of a Newtonian mass term, the Chern number of a pure Dirac system is given by $C_{\text{QED}} = \pm \text{sgn}(m)/2$ before regularization. Hence, it is half-quantized and always nonzero. In contrast, the Chern number in Eq. (3) is integer quantized and defines two different phases: For $m/B > 0$, the system is topologically nontrivial with $C_{\text{CI}} = \pm 1$, while for $m/B < 0$, the system is topologically trivial with $C_{\text{CI}} = 0$. In a solid-state system with a crystal lattice, Dirac fermions in $2 + 1$ space-time dimensions always come in pairs.⁵ The naive lattice discretization of a pure Dirac fermion leads to a phenomenon called fermion doubling, which predicts the existence of a second Dirac fermion of opposite Chern number at the edge of the lattice Brillouin zone. Thus, the entire system has Chern number zero and the parity anomaly of a single Dirac fermion cannot be measured. However, in his seminal work [1], Haldane found a way to circumvent this difficulty in a condensed-matter system. He proposed a way of how to realize a single Dirac fermion in the bulk spectrum of graphene by separately manipulating the two Dirac gaps at the K and K' points of the hexagonal lattice structure via a complex hopping parameter. In particular, this parameter allows to close only one of the Dirac gaps, whereas the other one remains open. Hence, his model suggests a way of how to realize a solid-state system which has a single gapless Dirac fermion in $2 + 1$ dimensions but still a nonzero Hall conductivity proportional to the integer Chern number $C_{\text{HM}} = [\text{sgn}(m_K) - \text{sgn}(m_{K'})]/2$. Here, m_K and $m_{K'}$ are the Dirac mass terms at the K and K' points in graphene, respectively.

While so far the Haldane model has not yet been realized in a solid-state material, a closely related QAH effect has been predicted in two-dimensional systems like (Hg,Mn)Te quantum wells or magnetically doped (Bi,Sb)Te thin films. In the vicinity of the bulk gap, these systems can be effectively described by the Bernevig-Hughes-Zhang (BHZ) model

$$\mathcal{H}_{\text{BHZ}} = \begin{pmatrix} \mathcal{H}_{\text{CI}}^+(\mathbf{k}) & 0 \\ 0 & \mathcal{H}_{\text{CI}}^-(-\mathbf{k}) \end{pmatrix}, \quad (4)$$

To respect the Galilean invariance of the system, any additional mass correction needs to be of even order in momentum. Essentially, the prefactor of the highest-order mass correction replaces the Newtonian mass parameter B in the Chern number Eq. (3). Since higher-order mass corrections do change the band curvature, they will also alter the nonquantized Hall response at finite temperatures and chemical potentials. However, they will only change this response quantitatively. In particular, they do not prevent the possible gap closing apart from the Γ point which drives the low-energy response studied in this paper [cf. Eq. (19)].

⁵If the $(2 + 1)$ -dimensional manifold is the boundary theory of a $(3 + 1)$ -dimensional bulk, there could also be an odd number of Dirac fermions living at the boundary. For instance, this is the case at the boundary of $(3 + 1)$ -dimensional topological insulators. However, we are not considering such systems but focus our analysis on pure $(2 + 1)$ -dimensional bulk materials.

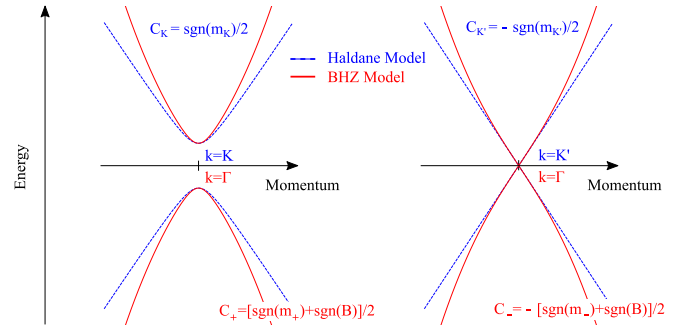


FIG. 1. Schematic illustration of how a single Dirac fermion or Chern insulator realizes the parity anomaly in the Haldane (blue) or BHZ (red) model. In the Haldane model, both Dirac fermions at the K and K' points of the hexagonal lattice structure contribute $\pm \frac{1}{2}$ to Chern number, whereas in the QAH phase of the BHZ model only one of the Chern insulators is topologically nontrivial and has a finite Chern number $C = \pm 1$. More explanations are given in the text.

which consists of two copies of the Chern insulators defined in Eq. (2). Since for the scope of this work, off-diagonal bulk inversion asymmetry terms which couple the two Chern insulators are unimportant, we are neglecting them throughout the paper. The \pm index of each Chern insulator in particular defines its (pseudo)spin polarization

$$\mathcal{H}_{\text{CI}}^\pm = A(k_1\sigma_1 - k_2\sigma_2) \pm (m_\pm - B\alpha)\sigma_3 - D\alpha\sigma_0. \quad (5)$$

In comparison to Eq. (2), Eq. (5) also includes a particle-hole asymmetry $D\alpha\sigma_0$. Since this term is parity even, it neither contributes to the parity anomaly nor changes the Chern number in Eq. (3) [36]. Therefore, let us first consider particle-hole symmetric systems with $D=0$. The Dirac masses m_\pm of each (pseudo)spin block in Eq. (5) can be tuned by magnetic doping of the system. It is in particular possible to drive one of the Chern insulators in the topologically trivial regime and to close, at the same time, the gap of the second nontrivial Chern insulator. Analogously to the Haldane model, in this scenario the single gapless Chern insulator alone realizes the parity anomaly of a Dirac-type system in $2 + 1$ dimensions. Schematically, this limit is illustrated in Fig. 1.

However, while in the Haldane model both Dirac fermions contribute $\pm \frac{1}{2}$ to the Chern number, in the QAH phase of the BHZ model only one of the Chern insulators has Chern number $C_{\text{CI}} = \pm 1$. The other one is topologically trivial with $C_{\text{CI}} = 0$. Hence, studying the single Chern insulator in Eq. (2) is sufficient to analyze the consequences of the parity anomaly in experimentally realizable systems like (Hg,Mn)Te quantum wells or magnetically doped (Bi,Sb)Te thin films.

The spectrum associated to Eq. (2) is given by

$$\epsilon^\pm(\alpha) = \pm \sqrt{A^2\alpha + (m - B\alpha)^2}, \quad (6)$$

where \pm encodes the conduction and the valence band, respectively. In Fig. 2, we show the influence of the mass parameters on the band structure. Depending on the values for m , B , and A , the band structure changes significantly. For $m/B > 0$, the system is topologically nontrivial with $C_{\text{CI}} = \pm 1$. The minimal gap can be either located at the Γ point or at $\alpha_{\text{min}} = (2mB - A^2)/(2B^2)$, corresponding to a camel-back structure.

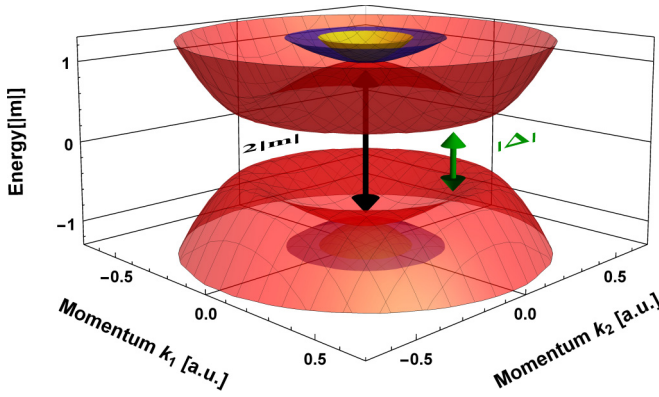


FIG. 2. Band structure of a Chern insulator for zero magnetic field and $D=0$. Red and blue curves encode topologically nontrivial phases with $m=A=1$, and $B=5$ (red, camel-back), or $m=1$, $A=3$, and $B=0.1$ (blue). The yellow curve corresponds to a topologically trivial phase with $m=1$, $A=5$, and $B=-0.1$. The minimal gap is either defined by $2|m|$ at the Γ point or by $|\Delta|$ at $\alpha = \alpha_{\min}$, indicated by the black or green arrow, respectively.

Thus, it is defined by $2|m|$ or by the absolute value of

$$\Delta = A\sqrt{4mB - A^2}/B. \quad (7)$$

Increasing $|m|$ or $|B|$ in the nontrivial phase leads to a camel-back structure if $2mB > A^2$, associated to $\alpha_{\min} > 0$. The camel-back gap $|\Delta|$ increases with m but decreases with B . For $4mB = A^2$, Δ vanishes and the spectrum simplifies to

$$\epsilon^\pm(\alpha) = \pm|(m + B\alpha)|. \quad (8)$$

For $m/B < 0$, the system is topologically trivial. In this case, the minimal gap is always located at the Γ point.

If we include an out-of-plane magnetic field H , a LL spectrum forms if the magnetic length $l_H = \sqrt{\hbar}/|eH|$ is smaller than the system size [37]. For $s = \text{sgn}(eH)$ and a finite particle-hole asymmetry D , one obtains

$$\epsilon_{n \neq 0}^\pm = -s\beta/2 - n\delta \pm \lambda_n, \quad (9)$$

$$\epsilon_0 = s(m - \beta/2) - \delta/2. \quad (10)$$

Here, we defined $\alpha = \sqrt{2}A/l_H$, $\beta = 2B/l_H^2$, $\delta = 2D/l_H^2$, and

$$\lambda_n = \sqrt{\alpha^2 n + (m - n\beta - s\delta/2)^2} \text{ with } n \in \mathbb{N}^+. \quad (11)$$

As shown in Ref. [13], H renormalizes the zero-field Chern number \mathcal{C}_{CI} in Eq. (3) to

$$\mathcal{C}_{\text{CI}}(H) = [\text{sgn}(m - B/l_H^2) + \text{sgn}(B)]/2. \quad (12)$$

Hence, a magnetic field counteracts the parity anomaly related contribution to the Chern number [Eq. (12)], which survives the parity-symmetric limit $m, B, H \rightarrow 0$. In particular, the magnetic field closes the Dirac mass gap at $H_{\text{crit}} = \text{sgn}(eH)m/B$. Beyond this critical magnetic field, the parity anomaly vanishes.

This highly nontrivial statement deserves further clarification. The parity anomaly of a single Chern insulator is a zero magnetic field effect. It is directly related to the parity-breaking elements of the zero-field Hamiltonian in Eq. (2) and its band structure in Fig. 2. In quantizing magnetic fields, the

Chern number of each LL only results from the magnetic field as it only depends on the magnetic length l_H . Nevertheless, the parity anomaly still has significant consequences in magnetic fields. Namely, it defines the Chern number in the Dirac mass gap [Eq. (12)], resulting from the spectral asymmetry of the entire LL spectrum [13]. Since for $|H| > |H_{\text{crit}}|$ the spectral asymmetry vanishes, there are no measurable consequences of the parity anomaly beyond this value.

Above, we have introduced the concept of Chern insulators and have discussed their concrete relation to the parity anomaly in $2+1$ space-time dimensions. Next, we study finite-temperature and density effects on the parity anomaly induced transport by calculating the Hall conductivity in zero, as well as in finite out-of-plane magnetic fields.

III. ANOMALY-INDUCED TRANSPORT IN ZERO MAGNETIC FIELD

In what follows, we calculate the finite-temperature Hall conductivity σ_{xy} corresponding to a particle-hole symmetric Chern insulator at zero magnetic field. This parity-odd and nondissipative transport coefficient is directly related to the parity anomaly in $2+1$ space-time dimensions as it does not vanish in the parity-symmetric limit $m, B \rightarrow 0^\pm$. In our calculation, we disentangle topological from nontopological contributions to σ_{xy} , the latter originating from thermal effects. For $D=0$, the finite-temperature Hall conductivity of the Chern insulator in Eq. (2) is given by [9]

$$\sigma_{xy}(T, \mu) = -\frac{e^2}{h} \int_0^\infty d\alpha \frac{A^2(m + B\alpha)[f_v(T, \mu) - f_c(T, \mu)]}{4[A^2\alpha + (m - B\alpha)^2]^{3/2}}, \quad (13)$$

where $f_{c,v}(T, \mu) = [e^{\epsilon^\pm(\alpha) - \mu}/(k_B T) + 1]^{-1}$ are the conduction and valence band Fermi functions [18]. This result is obtained by calculating the vacuum polarization operator or, analogously, the current-current correlation function. In the language of quantum field theory, this corresponds to the evaluation of a one-loop Feynman diagram, whereas in the solid-state community Eq. (13) results from the Kubo formalism. To disentangle topological from thermal contributions to σ_{xy} , we use that

$$f_v(T, \mu) = 1 - \frac{\Theta(-\epsilon) e^{(\epsilon - \mu)/(k_B T)}}{e^{(\epsilon - \mu)/(k_B T)} + 1}, \quad (14)$$

where $\epsilon(\alpha)$ encodes the entire spectrum and Θ is the Heaviside step function. With this identity, Eq. (13) decomposes into two building blocks,

$$\sigma_{xy}(T, \mu) = \sigma_{xy}^0 + \sigma_{xy}^1(T, \mu) \quad (15)$$

with

$$\sigma_{xy}^0 = -\frac{e^2}{2h} [\text{sgn}(m) + \text{sgn}(B)], \quad (16)$$

$$\begin{aligned} \sigma_{xy}^1(T, \mu) &= \frac{e^2}{h} \int d\alpha \frac{A^2(m + B\alpha) \text{sgn}(\epsilon)}{4\pi\epsilon^3} \\ &\times \left(\frac{\Theta(\epsilon)}{e^{(\epsilon - \mu)/(k_B T)} + 1} + \frac{\Theta(-\epsilon)}{e^{-(\epsilon - \mu)/(k_B T)} + 1} \right). \end{aligned} \quad (17)$$

Notice that due to the parity anomaly, neither Eq. (16) nor Eq. (17) necessarily vanish in the parity-symmetric limit $m, B \rightarrow 0$. Equation (16) encodes the topological part of the Hall conductivity. In contrast, Eq. (17) defines the corrections originating from a finite temperature and chemical potential. These nontopological and thus nonquantized corrections are based on particle-hole excitations of the conduction and valence bands. To solve Eq. (17), we use the assumption of a particle-hole symmetric Chern insulator with $D=0$. In particular, this implies

$$\sigma_{xy}^1(T, \mu) = \sigma_{xy}^{\text{corr}}(T, \mu) + \sigma_{xy}^{\text{corr}}(T, -\mu). \quad (18)$$

To determine $\sigma_{xy}^{\text{corr}}(T, \mu)$ in the energy space, we need to solve Eq. (6) for α . Due to the possible camel-back structure, this leads to two solutions

$$\alpha_{\pm} = \alpha_{\min} \pm \frac{\sqrt{\epsilon^2 - \Delta^2}}{|B|} \quad \text{with} \quad \frac{d\alpha_{\pm}}{d\epsilon} = \pm \frac{\epsilon}{|B|\sqrt{\epsilon^2 - \Delta^2}}.$$

With these identities, we find the correction

$$\begin{aligned} \sigma_{xy}^{\text{corr}}(T, \mu) = & \frac{e^2}{2h} \Theta[\alpha_{\min}] \int_{|\Delta|}^{\sqrt{m^2}} \frac{A^2 + \frac{2|B|\Delta^2}{\sqrt{\epsilon^2 - \Delta^2}}}{B\epsilon^2(e^{(\epsilon-\mu)/T} + 1)} d\epsilon \\ & + \frac{e^2}{4h} \int_{\sqrt{m^2}}^{\infty} \frac{A^2 + \frac{2|B|\Delta^2}{\sqrt{\epsilon^2 - \Delta^2}}}{B\epsilon^2(e^{(\epsilon-\mu)/T} + 1)} d\epsilon. \end{aligned} \quad (19)$$

While in Eq. (19) the second term captures the correction from a monotonic band structure, the first term encodes a possible camel-back correction. For $4mB = A^2$ with $\Delta = 0$, $\sigma_{xy}^{\text{corr}}(T, \mu)$ reduces to

$$\sigma_{xy}^{\text{corr}}(T, \mu) = \frac{me^2}{h} \int_{\sqrt{m^2}}^{\infty} \frac{A^2}{\epsilon^2(e^{(\epsilon-\mu)/(k_B T)} + 1)} d\epsilon, \quad (20)$$

which is twice the QED₂₊₁ result with $B = 0$. Analogously to Eq. (16), the Newtonian mass provides a factor of 2 to the thermal corrections of the QED₂₊₁ conductivity. For the solution in Eq. (20), we can define the corrections in terms of the gamma function $\Gamma(x)$ and the reduced Fermi-Dirac integral $F_j(x, b)$ (see Appendix A). In total, this leads to

$$\begin{aligned} \sigma_{xy}^1(T, \mu) = & \frac{e^2}{h} \sum_{s=\pm} \frac{A^2 \Gamma(-1) F_{-2}\left(\frac{s\mu}{k_B T}, \frac{|m|}{k_B T}\right)}{k_B T} \\ \stackrel{T \ll |m|}{\approx} & \frac{e^2 A^2 \Gamma\left(-1, \frac{|m|}{k_B T}\right)}{h k_B T}. \end{aligned} \quad (21)$$

In Eq. (21), we approximate the result for low temperatures in comparison to the gap and for zero chemical potential. $\Gamma(s, b)$ is the incomplete gamma function (see Appendix A).

The general correction in Eq. (19) cannot be expressed via the integral functions above since $\Delta \neq 0$. In Fig. 3, we plot the functional dependence of $\sigma_{xy}(\mu, T)$ for different choices of m and B . While increasing the Dirac mass always counteracts the temperature, increasing B enhances temperature effects in the topologically nontrivial phase. As discussed below Eq. (7), this originates from the property that B decreases the camel-back gap. Thus, both masses contribute equally to the topological part of the Hall conductivity in Eq. (16),

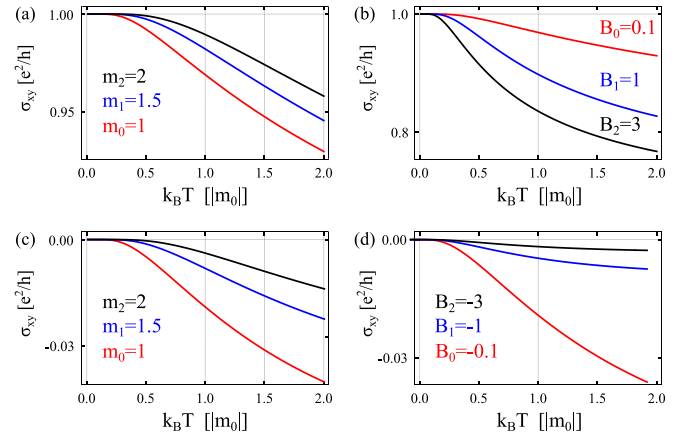


FIG. 3. Finite-temperature Hall conductivity of a Chern insulator with $A=1$ and $D=0$. In (a) and (c), we vary the Dirac mass while $B = \pm 0.1$, respectively. In (b) and (d), we vary the Newtonian mass for $m=1$. In all subfigures we consider zero chemical potential. (a), (b) Correspond to the topologically nontrivial regime, while (c) and (d) correspond to the topologically trivial regime.

while they counteract each other in the thermal corrections [Eq. (17)] for $m/B > 0$. Notice, that even in the topologically trivial phase $m/B < 0$ the system has a finite Hall conductivity in the Dirac mass gap [cf. Figs. 3(c) and 3(d)]. This is also directly related to the parity anomaly since it arises from the broken parity symmetry of the band structure, which is independent of $\text{sgn}(m/B)$. However, in the topologically trivial phase the Newtonian mass cannot generate a camel-back structure. In this case, both the Dirac and the Newtonian mass terms counteract the finite-temperature broadening of the Fermi-Dirac distribution.

IV. ANOMALY-INDUCED TRANSPORT IN FINITE MAGNETIC FIELDS

Having analyzed a particle-hole symmetric Chern insulator at zero magnetic field, we now include a particle-hole asymmetry and an out-of-plane magnetic field H , where the latter gives rise to the LL spectrum in Eq. (9). The Hall conductivity can be calculated by means of Streda's formula via the expectation value of the charge operator $\langle N \rangle_{T, \mu}$ [14, 38], yielding

$$\sigma_{xy}(T, \mu) = -\frac{\partial \langle eN \rangle_{T, \mu}}{\partial H} = \frac{e}{2} \frac{\partial \eta_H}{\partial H} - \frac{\partial \langle eN_0 \rangle}{\partial H}. \quad (22)$$

Here, $\epsilon_z = -mD/B$ is the charge neutrality point, and

$$\eta_H = \sum_n \text{sgn}(\epsilon_n - \epsilon_z) = -\frac{eH}{h} [\text{sgn}(m - \beta/2) + \text{sgn}(B)],$$

$$\langle N_0 \rangle = \sum_n \text{sgn}(\epsilon_n - \epsilon_z) \left[\frac{\Theta(\epsilon_n - \epsilon_z)}{e^{\frac{\epsilon_n - \mu}{k_B T}} + 1} + \frac{\Theta(\epsilon_z - \epsilon_n)}{e^{-\frac{\epsilon_n - \mu}{k_B T}} + 1} \right]. \quad (23)$$

The spectral asymmetry η_H counts the difference in the number of conduction and valence band states. Therefore, as long as the band structure is not changed, it is temperature and chemical potential independent and solely carries the information of the topological contribution of the parity anomaly to σ_{xy} in magnetic fields. This enables the connection between the Hall conductivity and the parity anomaly even at finite

magnetic fields. In contrast, $\langle N_0 \rangle$ encodes the thermal LL response, as it defines the thermal occupation of the valence and the conduction bands. Due to the associated flat dispersion relation, this response entirely originates from the magnetic field topology and no more from the parity anomaly. All LLs with $n \in \mathbb{N}^+$ come in pairs. With the degeneracy $|eH|/h$, their contribution to the charge operator is given by

$$\langle N_0 \rangle_{n \neq 0} = \frac{|eH|}{h} \sum_{n \neq 0, s = \pm} \frac{s}{e^{\frac{s(\epsilon_0 - \mu)}{k_B T}} + 1}. \quad (24)$$

Additionally to this conventional LL response for finite μ and T , the zero LL also needs to compensate its contribution to η_H outside of the Dirac mass gap. In particular, it needs to cancel the term $\alpha \text{sgn}(m - \beta/2)$ in Eq. (23) for $|\mu + \delta/2| > |m - \beta/2|$ [13]. Since the zero LL can either be part of the conduction or of the valence band, we can simplify its contribution to $\langle N_0 \rangle$. By using the properties of the hyperbolic tangent, we find for the zero LL with $n = 0$

$$\langle N_0 \rangle_0 = -\frac{|eH| \text{sgn}(\epsilon_0 - \epsilon_z)}{2h} \left[\Theta(\epsilon_0 - \epsilon_z) \left[\tanh\left(\frac{\epsilon_0 - \mu}{2k_B T}\right) - 1 \right] - \Theta(\epsilon_z - \epsilon_0) \left[\tanh\left(\frac{\epsilon_0 - \mu}{2k_B T}\right) + 1 \right] \right].$$

This expression can be simplified further via the identities

$$\begin{aligned} \text{sgn}(\epsilon_0 - \epsilon_z) &= \text{sgn}(\epsilon_0 + \delta/2) = \text{sgn}(eH) \text{sgn}(m - \beta/2), \\ \Theta(\epsilon_0 - \epsilon_z) - \Theta(-\epsilon_0 + \epsilon_z) &= \text{sgn}(\epsilon_0 - \epsilon_z), \\ \Theta(\epsilon_0 - \epsilon_z) + \Theta(-\epsilon_0 + \epsilon_z) &= 1. \end{aligned} \quad (25)$$

Eventually, this implies the zero LL contribution

$$\langle N_0 \rangle_0 = \frac{|eH|}{2h} \left[\text{sgn}(eH) \text{sgn}(m - \beta/2) - \tanh\left(\frac{\epsilon_0 - \mu}{2k_B T}\right) \right], \quad (26)$$

which reduces for $T \rightarrow 0$ and $\bar{\mu} = \mu + D/l_H^2$ to (see Appendix A)

$$\begin{aligned} \langle N_0 \rangle_0 &= \frac{|eH|}{2h} \Theta(|\bar{\mu}| - |m - \beta/2|) \\ &\times [\text{sgn}(eH) \text{sgn}(m - \beta/2) + \text{sgn}(\bar{\mu})]. \end{aligned} \quad (27)$$

For $T=0$, the zero LL contribution to η_H clearly gets compensated outside of the Dirac mass gap. As expected, finite-temperature effects soften this property.

In Fig. 4, we used Eq. (22) to connect the charge operator to σ_{xy} and plotted the Hall conductivity corresponding to the parity anomaly and to each LL, separately. Moreover, we show the entire signal as a function of the chemical potential. While the Hall conductivity contribution related to the parity anomaly is T and μ independent, each LL comes along with an exponentially suppressed temperature broadening. Consequently, all LLs contribute to the Hall conductivity in the Dirac mass gap. This renormalizes the zero-temperature violation of the Onsager relation⁶ discussed recently in Ref. [13].

⁶At $T = 0$, the only contribution to the Hall conductivity in the Dirac mass gap is given by the parity anomaly in terms of the spectral asymmetry η_H [cf. Eq. (22)]. Due to Eq. (23) this contribution clearly

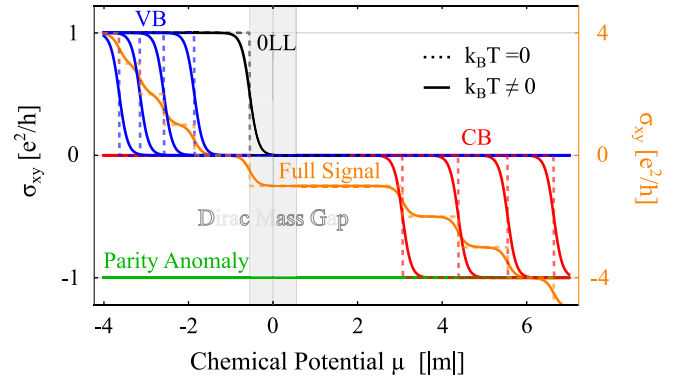


FIG. 4. Finite-temperature Hall conductivity of a Chern insulator in a magnetic field $H = 3T$ with $A = 1$, $m = -1$, $B = -0.1$, and $D = -0.05$. The response of each valence (blue) and conduction band (red) LL is shown separately. The zero LL response is illustrated in black, the parity anomaly related contribution is depicted in green. The combined signal is shown in orange. Dashed lines correspond to $k_B T = 0$, solid lines are associated to $k_B T = 0.01$. The Dirac mass gap is shown in gray.

Let us emphasize that the Hall plateau originating from the parity anomaly is much more robust than LL plateaus with respect to finite-temperature effects. In the Dirac mass gap all LL contributions to the Hall conductivity are exponentially suppressed. Due to the lack of a zero-LL partner, the parity anomaly response is approximately unaltered even beyond this gap, until the chemical potential comes close to the $n = 1$ conduction or valence band LL, depending on the sign of the magnetic field. Quantitatively, this means

$$|\epsilon_1^+ - \epsilon_0| > |\epsilon_{n+1}^\pm - \epsilon_n^\pm| \quad \forall n \in \mathbb{N}^+, \quad (28)$$

assuming that the zero LL is part of the valence band (cf. Fig. 4). Therefore, finite-temperature effects first smear out the LL steps before they eventually prevent any quantization for the finite-temperature Hall conductivity.

V. SUMMARY AND OUTLOOK

In this work we analyzed the finite-temperature Hall conductivity of two-dimensional Chern insulators under the influence of a chemical potential and an out-of-plane magnetic field. At zero magnetic field, this quantity originates from the parity anomaly, as it persists the parity-symmetric limit. As such, we were able to show that the parity anomaly is not renormalized by finite-temperature effects. Instead, it induces two terms of different physical origin in the effective action of a Chern insulator, which add up to its Hall conductivity. The first term is temperature and chemical potential independent, solely encoding the intrinsic topological response. The second term specifies the nontopological thermal response of conduction and valence band states. We showed that in the topologically nontrivial phase, an increasing relativistic mass term of a Chern insulator counteracts

violates the Onsager relation defined as $\sigma_{xy}(-H) = -\sigma_{xy}(H)$. In contrast, this identity is fulfilled by any (thermal) LL contribution.

finite-temperature effects, whereas an increasing nonrelativistic mass term enhances these corrections. In contrast, both mass terms counteract the finite-temperature broadening of the Fermi-Dirac distribution in the topologically trivial phase, as the Newtonian mass cannot cause a camel-back gap in this case. In magnetized II-VI QAH insulators, like (Hg,Mn)Te quantum wells, these parameters can be tuned by changing the quantum well width, or by changing the concentration of the magnetic dopants. Moreover, we derived the thermal response of a Chern insulator in a magnetic field and clarified its relation to the spectral asymmetry η_H . This quantity is a measure of the parity anomaly in magnetic fields. In particular, we derived in which way the thermal LL response renormalizes the parity anomalous part of the Hall conductivity in magnetic fields. Especially in the Dirac mass gap, this response adds to the otherwise quantized and temperature-independent part of the Hall conductivity arising from the parity anomaly. We showed that the anomalous part of the Hall response in the Dirac mass gap is much more robust than the common LL contributions with respect to finite-temperature effects. Our findings should be experimentally verifiable in QAH insulators such as (Hg,Mn)Te quantum wells, magnetically doped (Bi,Sb)Te thin films, or bilayer structures of three-dimensional topological and ferromagnetic insulators.

In the future, it would be interesting to extend this analysis to different anomalies in various space-time dimensions. For instance, the chiral, gravitational, and conformal anomaly should not depend on thermal effects, whereas they necessarily induce a temperature dependence at the effective action level.

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APPENDIX

The reduced Fermi-Dirac integral is defined by

$$F_j(x, b) = \frac{1}{\Gamma(j+1)} \int_b^\infty dt \frac{t^j}{e^{t-x} + 1}. \quad (A1)$$

The incomplete Γ function is defined by

$$\Gamma(s, b) = \int_b^\infty dt t^{s-1} e^{-t}. \quad (A2)$$

Let us comment on how to derive Eq. (27) from Eq. (26). In the zero-temperature limit, the hyperbolic tangent in Eq. (27) becomes a sign function $\lim_{T \rightarrow 0} \tanh(x/T) = \text{sgn}(x)$. Due to this property, we need to distinguish two cases. The chemical potential is either located inside (i) or outside (ii) of the Dirac mass gap:

$$(i) \quad |\mu + \delta/2| < |m - \beta/2|, \quad (A3)$$

$$(ii) \quad |\mu + \delta/2| > |m - \beta/2|. \quad (A4)$$

For case (i), the hyperbolic tangent in Eq. (27) reduces to $\text{sgn}(eH)\text{sgn}(m - \beta/2)$ and consequently leads to $\langle N_0 \rangle_0 = 0$. Instead, for case (ii), it reduces to $\text{sgn}(\mu + \delta/2)$, eventually implying Eq. (27). While the first, temperature-independent term in Eq. (27) describes the asymmetry of the zero LL with respect to zero energy, the second term encodes its temperature-dependent response. This term ensures that at $T=0$ the zero LL only contributes outside of the Dirac mass gap, exactly compensating its contribution to the spectral asymmetry. As expected, this property becomes softened by finite-temperature effects.

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